Digital Circuits & System

Course Objective
To learn the basic methods for the design of digital circuits and provide the fundamental Concepts used in the design of digital systems.
- To introduce basic postulates of Boolean algebra and shows the correlation between Boolean expressions
- To introduce the methods for simplifying Boolean expressions
- To outline the formal procedures for the analysis and design of combinational circuits and sequential circuits
- To introduce the concept of memories and programmable logic devices.
- To illustrate the concept of synchronous and asynchronous sequential circuits

Course contents:


Boolean postulates and laws – De-Morgan’s Theorem - Principle of Duality, Boolean function, Canonical and standard forms, Minimization of Boolean functions, Minterm, Maxterm, Sum of Products (SOP), Product of Sums (POS), Karnaugh map Minimization, Don’t care conditions, Quine-McCluskey method of minimization.


Logic Families: Introduction to different logic families and their characteristics, RTL, DTL, TTL, ECL, IIL, TTL inverter – circuit description and operation, CMOS inverter – circuit description and operation, other TTL and CMOS gates,
Memories – ROM - ROM organization - PROM – EPROM – EEPROM –EAPROM, RAM – RAM organization Static RAM, Dynamic RAM, Programmable Logic Array (PLA) - Programmable Array Logic (PAL)

Course outcome

Students who are successful in this class will demonstrate at least the abilities:
1. To introduce the concepts and techniques associated with the number systems and codes. To minimize the logical expressions using Boolean postulates.
2. To design various combinational and sequential circuits.

TEXT BOOKS

REFERENCES
1. Anil K. Maini, Digital electronics Principles and Integrated circuits Wiley India Pvt. Ltd.
2. Anandkumar- fundamental of digital circuit. 3rd edition. PHI

Graphical Programming using Lab
1. To verify the truth table of all basic logic gates and to implement all gate using universal gate.
2. Design of 4 bit Adders (CLA, CSA, CMA, Parallel adders)
3. Design of Binary Subtractor
4. Design of Encoder (8X3), Encoder(3X8)
5. Design of Multiplexer (8X1), and De-multiplexer (1X8)
6. Design of code converters & Comparator
7. Design of FF (SR, D, T, JK, and Master Slave with delays)
8. Design of registers using latches and flip-flops
COURSE OBJECTIVE:-
- To make the students capable of analyzing any given electrical network.
- To make the students learn how to synthesize an electrical network from a given impedance/admittance function.
- Understand the fundamental concepts and theories about networks.
- Apply this knowledge to solve real-world, network-centric problems.
- Use advanced network analysis methods and tools to visualize and analyze networks. Interpret the results with respect to exploratory, quantitative and substantive questions.
- Design and execute a small-scale network analysis project in a systematic fashion.

COURSE CONTENTS:-

**Introduction to circuit theory:** basic circuit element R,L,C and their characteristics in terms of linearity & time dependent nature, voltage & current sources, controlled & uncontrolled sources KCL and KVL analysis, Concept of phasor & vector, impedance & admittance, Nodal & mesh analysis, analysis of magnetically coupled circuits. Dot convention, coupling coefficient, tuned circuits, Series & parallel resonance.

**Network Graph theory:** Concept of Network graph, Tree, Tree branch & link, Incidence matrix, cut set and tie set matrices, dual networks.

**Network Theorems:** Thevenins & Norton’s, Super positions, Reciprocity, Compensation, Substitution, Maximum power transfer, and Millman’s theorem, Tellegen’s theorem, problems with dependent & independent sources.

**Transient analysis:** Transients in RL, RC&RLC Circuits, initial & final conditions, time constants. Steady state analysis

**Laplace transform:** solution of Integro-differential equations, transform of waveform synthesized with step ramp, Gate and sinusoidal functions, Initial & final value theorem, Network Theorems in transform domain.

**Two port parameters:** Z, Y, ABCD, Hybrid parameters, their inverse & image parameters, relationship between parameters, Interconnection of two ports networks, Reciprocity and Symmetry in all parameter.
EXPERIMENTS LIST:-
1. To Verify Thevenin Theorem and Superposition Theorem.
2. To Verify Reciprocity Theorem and Millman’s Theorem.
3. To Verify Maximum Power Transfer Theorem.
4. To Determine Open Circuit and Short Circuit parameters of a Two Port Network.
5. To Determine A, B, C, D parameters of a Two Port Network.
6. To determine h parameters of a Two Port Network.
7. To Find Frequency Response of RLC Series Circuit RLC parallel Circuit and determine resonance and 3dB frequencies.
8. To determine charging and discharging times of Capacitors.

COURSE OUTPUT:-
After successful completion of the course, student will be able to

- Apply the fundamental concepts in solving and analyzing different Electrical networks
- Select appropriate and relevant technique for solving the Electrical network in different conditions
- Apply mathematics in analyzing and synthesizing the networks in time and frequency domain
- Estimate the performance of a particular network from its analysis

TEXT BOOKS:-

1. M.E. Van Valkenburg, Network Analysis, (Pearson)

REFERENCE:-

1. Sudhakar-Circuit Network Analysis & Synth(TMH).
2. J. David Irwin Engineering Circuit analysis tenth edition, Wiley India.
3. Kuo- Network Analysis & Synthesis, Wiley India.
4. Robert L Boylestad introductory Circuit analysis, Pearson
6. Roy Choudhary D; Network and systems; New Age Pub.
PROGRAMME: B.E. Electronics & Communication Engineering, III-Semester
Electronic Devices & Circuits

COURSE OBJECTIVE: Any electronic trade has its basis on a certain number of components and some basic standard circuits. These common circuits are applied in all sections of the Electronics technology. A good understanding of the basic functioning of all these components and circuits will be a solid platform to enter into the more complex portion and specialized field of Electronics Engineering. Emphasis has been given on the characteristics and application of semiconductor devices/components. In the case of basic standard circuits, the focus has been made on the interaction of active and passive components and overall performance according to the stated requirements.

COURSE CONTENTS:
Introduction to semiconductor physics: insulator, conductor, semiconductor and semiconductor types. Drift and diffusion carries, Hall Effects.
Review of PN junction diode: PN junction diode in forward and reverse bias, temperature dependence of V-I characteristics, diode resistances, diode junction capacitance. Types of diodes: Zener Diode, Varactor Diode, Tunnel Diode, PIN Diode, Schottky Diode, LED and Photo Diodes, Switching characteristics of diode.

Bipolar junction transistor - Construction, basic operation, current components and equations, CB, CE and CC-configuration, input and output characteristics, Early effect, Region of operations: active, cut-off and saturation region. BJT as an amplifier. Ebers-Moll model, Power dissipation in transistor (Pd_max rating), Photo transistor.
Transistor biasing circuits and analysis: Introduction, various biasing methods: Fixed bias, Self bias, Voltage Divider bias, Collector to base bias, Load-line analysis: DC and AC analysis, Operating Point and Bias Stabilization and Thermal Runaway. Transistor as a switch.

Small Signal analysis: Small signal Amplifier, Amplifier Bandwidth, Hybrid model, analysis of transistor amplifier using h-parameter, Multistage Amplifier: Cascading amplifier, Bootstrapping Technique, Darlington amplifier and cascode amplifier, Coupling methods in multistage amplifier, Low and high frequency response, Hybrid π model, Current Mirror circuits.

Large Signal analysis and Power Amplifiers: Class A, Class B, Class AB, Class C, Class D, Transformer coupled and Push-Pull amplifier.

FET construction- JFET: Construction, n-channel and p-channel, transfer and drain characteristics, parameters, Equivalent model and voltage gain, analysis of FET in CG, CS and CD configuration. Enhancement and Depletion MOSFET drain and transfer Characteristics.
Uni-junction Transistor (UJT) and Thyristors: UJT: Principle of operation, characteristics, UJT relaxation oscillator, PNPN Diode and its characteristics, Silicon controlled rectifier: V-I characteristics, DIAC and TRIAC, Thyristors parameters and applications.

LIST OF EXPERIMENTS:
1. To determine and analyze the V-I characteristics of PN Junction diode and Zener diode.
2. To determine input and output characteristics of transistor amplifiers in CE, CB & CC configurations.
3. To determine the frequency response of transistor CE amplifier, direct coupled and RC coupled amplifier.
4. To determine characteristics of UJT as relaxation Oscillator.
5. To determine Drain and Transfer Characteristics of JFET Amplifier.
6. To determine Drain and Transfer Characteristics of MOSFET Amplifier.
7. To determine characteristics of class A and B power amplifiers.
8. To determine characteristics of class C and AB power amplifiers.

COURSE OUTCOMES:
Students who are successful in this class will be able to:
1. Understand the basic physics of carrier transport in bulk semiconductors and real device structures.
2. Understand the fundamentals of operation of the main semiconductor electronic devices.
3. Understand the basic parameters of electronic devices, their performance, and limiting factors.
4. Understand the basic principles of electronic device operation with emphasis on bipolar transistors, and unipolar microwave devices.

TEXTBOOKS
1. Millman and Halkias: Integrated electronics, TMH.
3. [Website Link]

REFERENCES:
4. Donald A Neamen: Electronic Circuits Analysis and Design, TMH
5. Salivahanan: Electronic Circuits Analysis and Design, TMH
6. Mottershead: Electronic Devices and Circuits an introduction, PHI
7. Kumar and Jain: Electronic Devices and Circuits, PHI.
8. David A. Bell Electronic Devices and Circuits Oxford University press.
COURSE OBJECTIVE:
This course is electronics based course dealing with measurements and instrumentation designed for students. The objectives of this course are to introduce students to the use of various electrical/electronic instruments, their construction, applications, and principles of operation, standards and units of measurements and provide students with opportunities to develop basic skills in the design of electronic equipments.

COURSE CONTENTS:

Different parts of CRO, Block diagram, Electrostatic focusing, Electrostatic deflection, Post deflection acceleration. Screen for CRTs, Graticules, Vertical and Horizontal deflection system, Time base circuit, Oscilloscope Probes, Applications of CRO, Special purpose CROs- Multi input, Dual trace, Dual beam, Sampling, Storage (Analog and Digital) Oscilloscope.

Maxwell’s bridge (Inductance and Inductance-Capacitance), Hay’s bridge, Schering bridge (High voltage and Relative permittivity), Wein bridge. Impedance measurement by Q-meter.

Non-Electrical Quantities (Transducer): Classification of Transducers, Strain gauge, Displacement Transducer- Linear Variable Differential Transformer (LVDT) and Rotary Variable Differential Transformer (RVDT), Temperature Transducer- Resistance Temperature Detector (RTD), Thermistor, Thermocouple, Piezo-electric transducer, Optical Transducer- Photo emissive, Photo conductive, Photo voltaic, Photo-diode, Photo Transistor.

Signal and Function Generators, Sweep Frequency Generator, Pulse and Square Wave Generator, Beat Frequency Oscillator, Digital display system and indicators, Classification of Displays, Display devices: Light Emitting diodes (LED) and Liquid Crystal Display (LCD). Advantages of Digital Instrument over Analog Instrument, Digital-to-analog conversion (DAC) - Variable resistive type, R-2R ladder Type, Binary ladder, Weighted converter using Op-amp and transistor, Practical DAC. Analog-to-digital Conversion (ADC) - Ramp Technique, Dual Slope Integrating Type, Integrating Type (voltage to frequency), Successive Approximations. Digital voltmeters and multi-meters, Resolution and sensitivity of digital multi-meter.

List of Experiments:
1. Study of Cathode Ray Oscilloscope and Function Generator.
2. Study of displacement measurement by LVDT.
3. Force measurement by strain gauge.
6. Temperature measurement by thermistor, RTD and thermocouple.
7. Study of optical Transducers: Photo conductive, Photo voltaic, Photo-diode, Photo-Transistor.
8. Design of digital to analog converter, R-2R ladder Type and analysis of its characteristics.

**COURSE OUTPUT:**
Upon successful completion of this course, the student will be able to:
- Identify electronics/ electrical instruments, their use, peculiar errors associated with the instruments and how to minimize such errors.
- Explain the industrial and laboratory applications of such instruments.
- Service and maintain such instruments in case of damage or misuse.
- Understand the basic design techniques of electronic equipment.

**TEXTBOOKS**

1. H.S. Kalsi: Electronics Instrumentation, TMH

**REFERENCES:**

1. Oliver: electronic Measurements introduction TMH
5. Banerjee: electrical and electronics Measurement 2nd PHI.
6. Anand: electronics and Instrumentation technology, PHI.